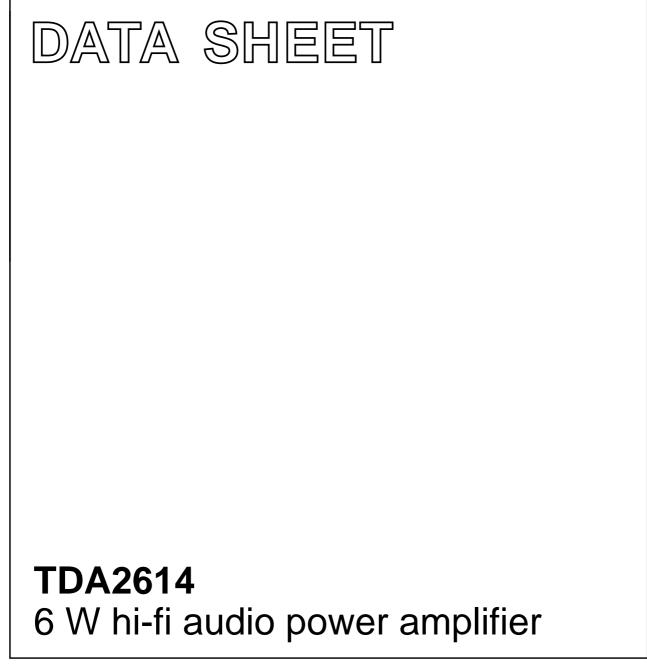
# INTEGRATED CIRCUITS



Product specification File under Integrated Circuits, IC01 July 1994



Philips Semiconductors

# TDA2614

### FEATURES

- Requires very few external components
- No switch-on/switch-off clicks
- Input mute during switch-on and switch-off
- Low offset voltage between output and ground
- Hi-fi in accordance with IEC 268 and DIN 45500
- Short-circuit proof and thermal protected
- Mute possibility.

### **GENERAL DESCRIPTION**

The TDA2614 is a power amplifier in a 9-lead single-in-line (SIL9) plastic medium power package. It has been especially designed for mains fed applications, such as TV and radio.

## QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>P</sub>	positive supply voltage range		15	_	42	V
Po	output power	V <sub>S</sub> = 24 V; THD = 0.5%	-	6.5	-	W
G <sub>v</sub>	internal voltage gain		_	30	_	dB
SVRR	supply voltage ripple rejection		_	45	_	dB
V <sub>no</sub>	noise output voltage		-	70	_	μV

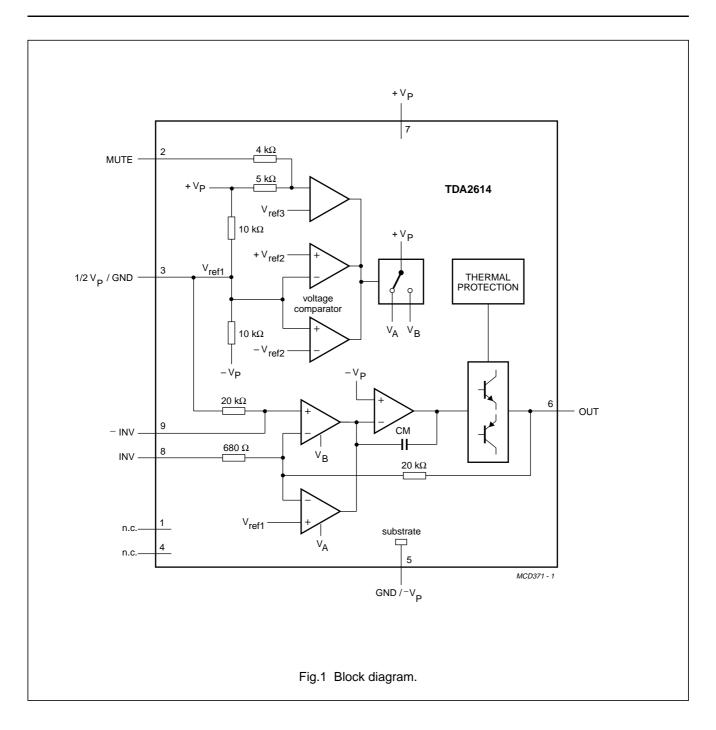
### **ORDERING INFORMATION**

EXTENDED TYPE	PACKAGE				
NUMBER	PINS	PIN POSITION	MATERIAL	CODE	
TDA2614	9	SIL	plastic	SOT110 <sup>(1)</sup>	

#### Note

1. SOT110-1; 1996 August 21.

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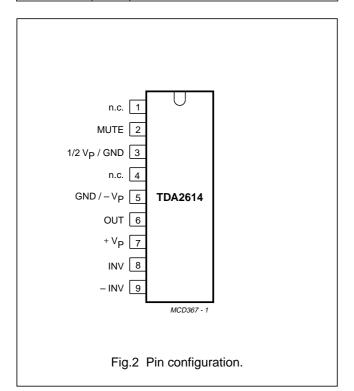


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### TDA2614

### PINNING

SYMBOL	PIN	DESCRIPTION
n.c.	1	not connected
MUTE	2	mute input
1/2V <sub>P</sub> /GND	3	1/2 supply (or ground at symmetrical power supplies)
n.c.	4	not connected
GND/–V <sub>P</sub>	5	ground (or negative supply rail at symmetrical power supplies)
OUT	6	output
V <sub>P</sub>	7	supply voltage
INV	8	inverting input
-INV	9	non-inverting input



### FUNCTIONAL DESCRIPTION

The TDA2614 is a hi-fi power amplifier designed for mains fed applications, such as radio and TV. The circuit is optimally designed for asymmetrical power supplies, but is also well-suited to symmetrical power supply systems.

An output power of 6 W (THD = 0.5%) can be delivered into an 8  $\Omega$  load with a supply of 24 V. The gain is internally fixed at 30 dB, thus offering a low gain spread.

A special feature is the input mute circuit. This circuit disconnects the non-inverting input when the supply voltage drops below 10 V, while the amplifier still retains its DC operating adjustment. The circuit features suppression of unwanted signals at the input, during switch-on and switch-off.

The mute circuit can also be activated via pin 2. When a current at 300  $\mu A$  is present at pin 2, the circuit is in the mute condition.

The device is provided with two thermal protection circuits. One circuit measures the average temperature of the crystal and the other measure the momentary temperature of the power transistors. These control circuits attack at temperatures in excess of 150 °C, so a crystal operating temperature of max. 150 °C can be used without extra distortion.

With the derating value of 8 K/W, the heatsink can be calculated as follows:

at  $R_L$  = 8  $\Omega$  and  $V_S$  = 24 V, dissipation is 4.1 W.

With a maximum ambient temperature of 60  $^{\circ}\text{C},$  the thermal resistance of the heatsink is:

$$R_{th} \; = \; \frac{150-60}{4.1} - 8 \; = \; 14 \; \text{K/W}.$$

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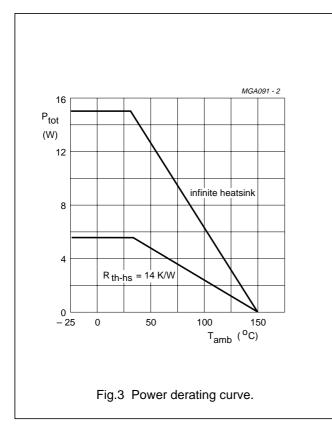
### LIMITING VALUES

In accordance with the Absolute maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>P</sub>	positive supply voltage		_	42	V
I <sub>OSM</sub>	non-repetitive peak output current		-	4	A
P <sub>tot</sub>	total power dissipation	see Fig.3	_	15	W
T <sub>stg</sub>	storage temperature range		-55	+150	°C
T <sub>XTAL</sub>	crystal temperature		-	+150	°C
T <sub>amb</sub>	ambient operating temperature range		-25	+150	°C
t <sub>sc</sub>	short circuit time	short circuit to ground; note 1	-	1	h

### Note to the limiting values

1. For asymmetrical power supplies (with the load short-circuited), the maximum unloaded supply voltage is limited to  $V_P = 28 \text{ V}$ , and with an internal supply resistance of  $R_S \ge 4 \Omega$ , the maximum unloaded supply voltage is limited to 32 V (with the load short-circuited). For symmetrical power supplies, the circuit is short-circuit-proof up to  $V_P = \pm 21 \text{ V}$ .



### THERMAL RESISTANCE

SYMBOL	PARAMETER	THERMAL RESISTANCE
R <sub>th j-c</sub>	from junction to case	8 K/W

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### CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Supply			•	•		
V <sub>P</sub>	supply voltage range		-	24	42	V
I <sub>ORM</sub>	repetitive peak output current		-	2.2	-	А
Operating	position; note 1		•	•		
V <sub>P</sub>	supply voltage range		15	24	42	V
IP	total quiescent current		10	20	35	mA
Po	output power					
		THD = 0.5%	5	6.5	_	W
		THD = 10%	6.5	8.5	_	W
		THD = 0.5%; $R_L$ = 4 $\Omega$	_	10	_	W
		THD = 10%; $R_L = 4 \Omega$	_	14	_	W
THD	total harmonic distortion	$P_0 = 4 W$	_	0.15	0.2	%
В	power bandwidth	THD = 0.5%; note 2	-	30 to	_	Hz
				20 000		
G <sub>v</sub>	voltage gain		29	30	31	dB
ΔV <sub>3-6</sub>	DC output offset voltage		-	30	200	mV
V <sub>no</sub>	noise output voltage	note 3	-	70	140	μV
Z <sub>i</sub>	input impedance		14	20	26	kΩ
SVRR	supply voltage ripple rejection	note 4	35	45	_	dB
I <sub>bias</sub>	input bias current		-	0.3	-	μA
MUTE POSI	τιον (at I <sub>MUTE</sub> ≥ 300 μA)			•	•	
Vo	output voltage	V <sub>I</sub> = 600 mV	-	0.1	1.0	mV
Z <sub>2-7</sub>	mute input impedance		_	9	-	kΩ
I <sub>P</sub>	total quiescent current		10	20	35	mA
V <sub>no</sub>	noise output voltage	note 3	-	70	140	μV
SVRR	supply voltage ripple rejection	note 4	35	44	_	dB
ΔV <sub>3-6</sub>	DC output offset voltage		-	40	200	mV
$ \Delta V_{off} $	offset voltage with respect to operating position		-	4	150	mV
l <sub>2</sub>	current if pin 2 is connected to pin 5		-	-	6	mA
Mute posi	tion; note 5		•	•	•	•
V <sub>P</sub>	positive supply voltage range		4	_	10	V
IP	total quiescent current	$R_L = \infty$	5	15	20	mA
Vo	output voltage	V <sub>I</sub> = 600 mV	_	0.1	1.0	mV
V <sub>no</sub>	noise output voltage	note 3	-	70	140	μV
SVRR	supply voltage ripple rejection	note 4	35	44	-	dB
ΔV <sub>3-6</sub>	DC output offset voltage		_	40	200	mV

### TDA2614

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Operating	position; note 6					
±VP	supply voltage range		7.5	12	21	V
I <sub>P</sub>	total quiescent current		10	20	35	mA
Po	output power					
		THD = 0.5%	5	6.5	_	W
		THD = 10%	6.5	8	_	W
THD	total harmonic distortion	$P_0 = 4 W$	_	0.13	0.2	%
В	power bandwidth	THD = 0.5%; note 2	-	40 to	_	Hz
				20000		
G <sub>v</sub>	voltage gain		29	30	31	dB
V <sub>no</sub>	noise output voltage	note 3	-	70	140	μV
Z <sub>i</sub>	input impedance		14	20	26	kΩ
SVRR	supply voltage ripple rejection		40	55	_	dB
I <sub>bias</sub>	input bias current		-	0.3	_	μA
V <sub>GND</sub>	DC output offset voltage		-	30	200	mV
MUTE POSI	τιον (ατ Ι <sub>MUTE</sub> ≥ 300 μA)		·	•	•	•
Vo	output voltage	V <sub>I</sub> = 600 mV	-	0.1	1.0	mV
Z <sub>2-7</sub>	mute input impedance	note 7	6.7	9	11.3	kΩ
I <sub>P</sub>	total quiescent current	R <sub>L</sub> = ∞	10	20	35	mA
V <sub>no</sub>	noise output voltage	note 3	-	70	140	μV
SVRR	supply voltage ripple rejection	note 4	40	55	_	dB
$ \Delta V_{GND} $	DC output offset voltage		-	40	200	mV
$ \Delta V_{\text{off}} $	offset voltage with respect to operating position		-	4	150	mV
I <sub>2</sub>	current if pin 2 is connected to pin 5		_	_	6	mA

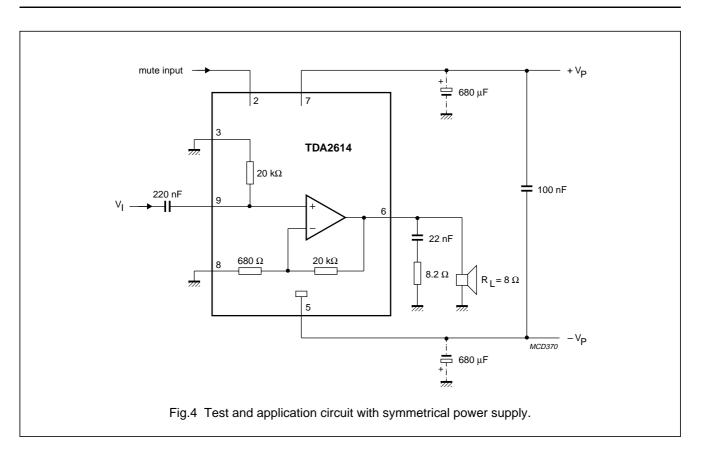
#### Notes to the characteristics

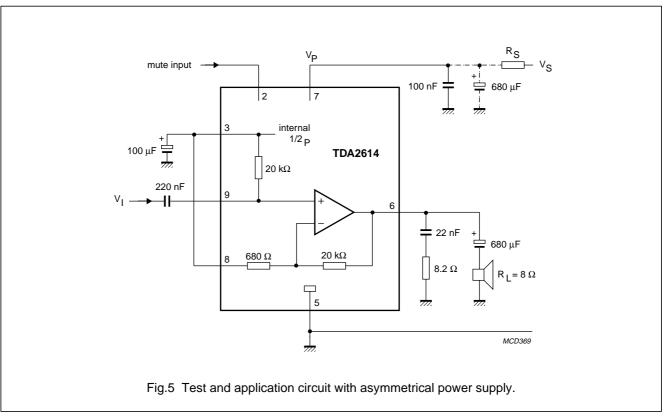
1.  $V_P = 24 \text{ V}$ ;  $R_L = 8 \Omega$ ;  $T_{amb} = 25 \text{ °C}$ ; f = 1 kHz; asymmetrical power supply  $I_{MUTE} < 30 \mu A$ . See Fig.5

- 2. The power bandwidth is measured at an output power of  $P_{O\,max}-3~\text{dB}.$
- 3. The noise output voltage (RMS value) is measured at  $R_S = 2 k\Omega$ , unweighted (20 Hz to 20 kHz).
- 4. The ripple rejection is measured at R<sub>S</sub> = 0 and f = 100 Hz to 20 kHz, at a ripple voltage of 200 mV. With symmetrical power supplies, the ripple (200 mV) is applied in phase to the positive and the negative supply rails. With asymmetrical power supplies, the ripple rejection is measured at f = 1 kHz.
- 5.  $V_P = 8 V$ ;  $R_L = 8 \Omega$ ;  $T_{amb} = 25 °C$ ; f = 1 kHz; asymmetrical power supply. See Fig.5
- 6.  $\pm V_P = 12 \text{ V}; \text{ R}_L = 8 \Omega; \text{ T}_{amb} = 25 \text{ °C}; \text{ f} = 1 \text{ kHz}; \text{ symmetrical power supply } I_{MUTE} < 30 \mu\text{A}.$  See Fig.4
- 7. The internal network at pin 2 is a resistor devider of typical 4 k $\Omega$  and 5 k $\Omega$  to the positive supply rail. At the connection of the 4 k $\Omega$  and 5 k $\Omega$  resistor a zener diode of typical 6.6 V is also connected to the positive supply rail. The spread of the zener voltage is 6.1 to 7.1 V.

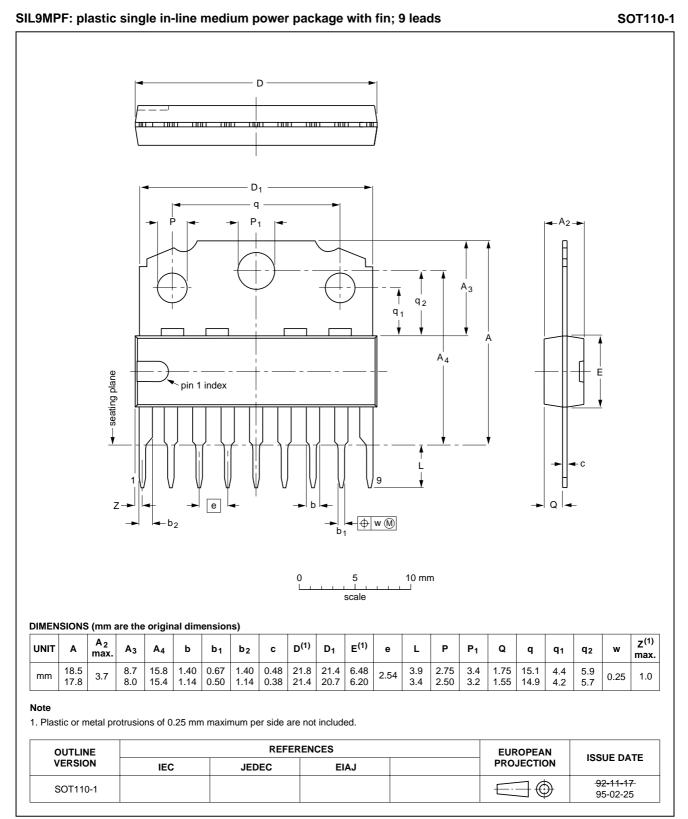
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## TDA2614





### PACKAGE OUTLINE



July 1994

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TDA2614

# TDA2614

### SOLDERING

### Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"IC Package Databook"* (order code 9398 652 90011).

#### Soldering by dipping or by wave

The maximum permissible temperature of the solder is 260 °C; solder at this temperature must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature ( $T_{stg\,max}$ ). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

### **Repairing soldered joints**

Apply a low voltage soldering iron (less than 24 V) to the lead(s) of the package, below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than 300 °C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 °C, contact may be up to 5 seconds.

### DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or				

more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### Application information

Where application information is given, it is advisory and does not form part of the specification.

#### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.